

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	("6764886").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 07:07
L2	4	("5409867" "5643826" "5795816" "5851862").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/11/17 07:21
L3	0	("6764886").URPN.	USPAT	OR	OFF	2004/11/17 07:44
L4	1028	257/57	USPAT	OR	OFF	2004/11/17 07:44
L5	2457	257/59	USPAT	OR	OFF	2004/11/17 07:45
L6	402	257/71	USPAT	OR	OFF	2004/11/17 07:45
L7	2005	257/72	USPAT	OR	OFF	2004/11/17 08:17
L8	3070	257/347	USPAT	OR	OFF	2004/11/17 07:46
L9	1679	257/350	USPAT	OR	OFF	2004/11/17 09:04
L10	1062	257/351	USPAT	OR	OFF	2004/11/17 07:46
L11	677	257/365	USPAT	OR	OFF	2004/11/17 07:46
L12	420	257/354	USPAT	OR	OFF	2004/11/17 07:47
L13	6	("5360749" "5591653" "5760442" "5910015" "5981345" "6124614").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/11/17 08:06
L14	3	("6403981").URPN.	USPAT	OR	OFF	2004/11/17 08:07
L15	10	("5604368" "5689127" "5773331" "5780327" "6013553" "6020024" "6166412" "6335214" "6403981" "6514826").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/11/17 08:07
L16	0	((thin adj film adj transistor) tft) with (gate adj electrode adj in adj substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:11
L17	0	((thin adj film adj transistor) tft) and (gate adj electrode adj in adj substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:07
L18	0	(gate adj electrode adj in adj substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:07
L19	10216	((thin adj film adj transistor) tft) and ((gate adj electrode) with substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:08

L20	4959	((thin adj film adj transistor) tft) with ((gate adj electrode) with substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:08
L21	33069	((thin adj film adj transistor) tft) with ((gate adj electrode) in substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:09
L22	7536	21 and "257"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:10
L23	6505	22 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:10
L24	0	((thin adj film adj transistor) tft) with ((gate adj electrode) adj in adj substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:11
L25	0	((gate adj electrode) adj in adj substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:12
L26	7	((gate adj electrode) adj within adj substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:17
L27	2	("5311040").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 09:17
L28	5	("4905066" "4933296" "4960719" "4979006" "5017983").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/11/17 09:18
L29	14	("5311040").URPN.	USPAT	OR	OFF	2004/11/17 09:18
S1	142	(257/258).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/16 14:44
S2	1574	(257/72).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/17 07:07
S3	8389	lai.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/16 14:45

S4	4	S3 and chien-ting	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/16 14:45
S5	2576	pang.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/16 14:55
S6	23	S5 and jia-pang	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/16 14:46
S7	7	("5894136" "5962896" "5962916" "5990492" "6046479" "6191452" "6281552").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/11/16 14:48
S8	87900	chen.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/16 14:55
S9	19	S8 and yung-chang	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/16 14:58
S10	2	("5349205").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/16 14:58
S11	5	("5036370" "5066106" "5162933" "5177577" "5187602").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/11/16 15:58
S12	17	("5349205").URPN.	USPAT	OR	OFF	2004/11/16 15:59
S13	5	("5349205" "5648293" "5840602" "5917564" "6599790").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/11/16 16:07
S14	0	("6753550").URPN.	USPAT	OR	OFF	2004/11/16 16:09